

Revision 0.71

SINGLE FREQUENCY LASER DIODES Distributed Bragg Reflector Laser



General Product Information

ment
91 nm)
of the laser in
ted by patents
2



Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	T_S	°C	-40		85
Operational Temperature at Case	T_{C}	°C	-20		75
Operational Temperature at Laser Chip	T_{LD}	°C	-5		25
Forward Current	I _F	mA			180
Reverse Voltage	V_R	V			2
Output Power	P_{opt}	mW			12
TEC Current	I _{TEC}	Α			1.1
TEC Voltage	V_{TEC}	V			2.8

Measurement Conditions / Comments

Stress in excess of one of the Absolute Maximum Ratings may damage the laser. Please note that a damaging optical power level may occur although the maximum current is not reached. These are stress ratings only, and functional operation at these or any other conditions beyond those indicated under Recommended Operational Conditions is not implied.

Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T_{case}	°C	0		50
Operational Temperature at Laser Chip	T_LD	°C	0		18
Forward Current	I _F	mA		100	160
Output Power	P_{opt}	mW			5

Measurement Conditions / Comments				
measured by integrated Thermistor				

Characteristics at T_{LD} = 15° at BOL

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm	632	633	634
Target Wavelength	λ_{T}	nm		632.991	
Linewidth (FWHM)	Δλ	MHz		1	
Sidemode Supression Ratio	SMSR	dB	30		
Temperature Coefficient of Wavelength	$d\lambda$ / dT	nm / K		0.045	
Current Coefficient of Wavelength	$d\lambda/dI$	nm / mA		0.001	

Measurement Conditions / Comments				
reached within T _{LD} = 0 ° 18° C at 10 mW				
$P_{opt} = 10 \text{ mW}$				





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Characteristics at T _{LD} = 15° at BOL						
Parameter	Symbol	Unit	min	typ	max	
Laser Current @ P _{opt} = 5 mW	I_{LD}	mA			160	
Slope Efficiency	η	W/A	0.1	0.4	0.7	
Threshold Current	I_{th}	mA		80	120	
Divergence parallel (FWHM)	$\Theta_{ }$	0		0.1		
Divergence perpendicular (FWHM)	Θ_{\perp}	0		0.1		
Beam Diameter horizontal	d	mm		0.7	1.0	
Beam Diameter vertical	d_\perp	mm		0.6	1.0	
Degree of Polarization	DOP	%		90		

Ith drift may occur, no violation of the max. value
parallel to the base plate of the housing (see p. 3)
perpendicular to base plate of the housing (see p. 3)
parallel to the base plate of the housing (see p. 3)
perpendicular to base plate of the housing (see p. 3)
$P_{\rm opt} = 10$ mW; E field perpendicular to base plate

Measurement Conditions / Comments

Monitor Diode					
Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	I _{mon} / P _{opt}	μΑ/mW	5		200

Measi	urement Conditions / Comments
$J_R =$	5 V

Thermoelectric Cooler					
Parameter	Symbol	Unit	min	typ	max
Current	I _{TEC}	А		0.7	1.1
Voltage	U_TEC	V		1.7	2.8
Power Dissipation (total loss at case)	P _{loss}	W		0.4	0.5
Temperature Difference	ΔΤ	K			60

Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			3892	
Steinhart & Hart Coefficient A	А			1.1293 x 10) -3
Steinhart & Hart Coefficient B	В		2.3410 x 10 ⁻⁴		
Steinhart & Hart Coefficient C	C			8.7755 x 10) -8

Measurement Conditions / Comments		
$T_{LD} = 25^{\circ} C$		
$R_1/R_2 = e^{\beta(1/T_1\cdot1/T_2)}$ at $T_{LD} =$	0° 50° C	
$1/T = A + B(\ln R) + C(\ln R)^3$		
T: temperature in Kelvin		
R: resistance at T in Ohm		



Thermistor (Standard NTC Type)



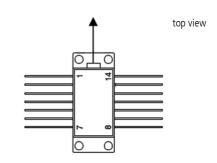
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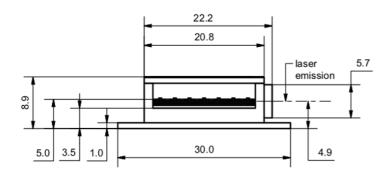


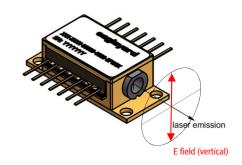
	nmen	

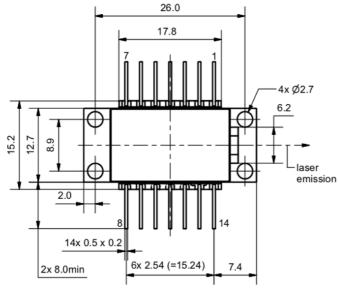
1	Thermoelectric Cooler (+)	14	Thermoelectric Cooler (-)	
2	Thermistor	13	Case	
3	Photodiode (Anode)	12	not connected	
4	Photodiode (Cathode)	11	Laser Diode (Cathode)	
5	Thermistor	10	Laser Diode (Anode)	
6	not connected	9	not connected	
7	not connected	8	not connected	
Pins are isolated from case unless noted otherwise.				



Package Drawings







DNV-GL



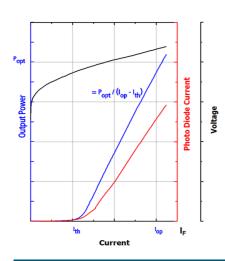
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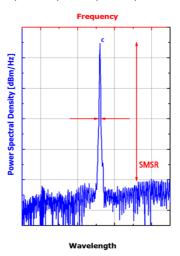


Typical Measurement Results

Output Power vs. Current



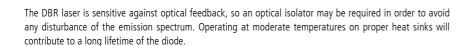
Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.



Avoid direct and/or indirect exposure to the free running beam. Collimating and focussing the free running beam with optics as common in optical instruments will increase threat to the human eye.

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